TONE/PULSE SWITCHABLE DIALER WITH LCD INTERFACE

GENERAL DESCRIPTION

The EM91203 is a series of tone/pulse switchable dialers that is composed of T/P dialer and T/P dialer with 3 sets memories. The EM91203 series provides necessary functions of telephone set for application in any environment, such as Pulse dialing, Tone (DTMF) dialing, Handfree dialing, keying tone, mute and pulse mute functions. Beside this, SDO (Serial Data Output) functions is provided in advance version that is designed to drive LCD driver and voice synthesizer. In this application, the dialing numbers can be displayed on LCD screen with EM32100 (or EM32116).

FEATURES

- Tone/Pulse switchable.
- Wide operating voltage from 2.0 V to 5.5 V.
- Low operating current, 0.15 mA (Pulse) and 0.3 mA (Tone) typically.
- Adding resistor on keyboard scan pin that can select many telephone specifications, such as: Pulse rate, M/B ratio, Flash time, Pause time, P-T wait time and keyboard type.
- SDO function supports LCD driver and voice synthesizer to indicate dialing numbers.
- Handfree function provides on-hook dialing and speakerphone application.
- 3-set one touch repertory memory, each one can store data up to 16 digits.
- A 32-digit LNB (last number) redial memory.
- A 32-digit SAVE redial memory.
- Keytone function provides rapidly keying recognition.
- Pulse mute function supports pulse dialing application.
- Using 3.579545 MHz crystal or ceramic resonator.
- Package forms: PDIP, skinny.

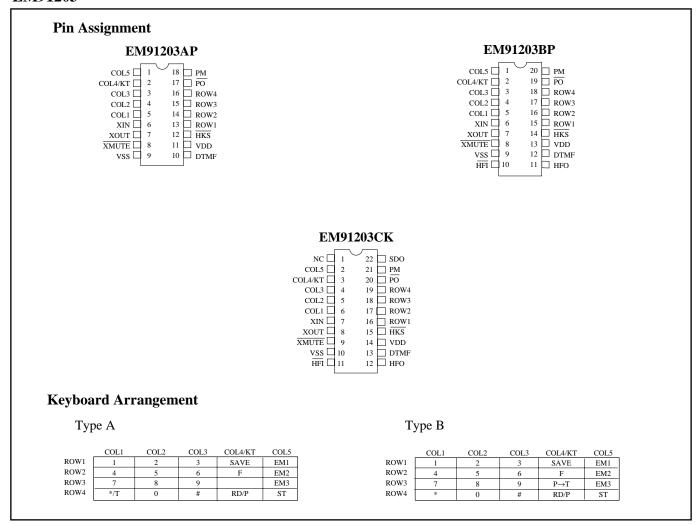
ORDERING INFORMATION

Versions list

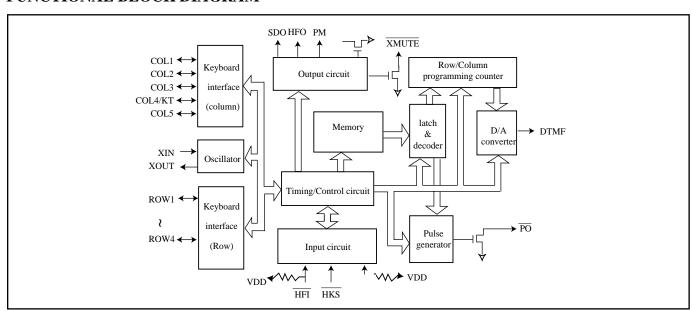
VERSION	LNB	KT	SAVE	HF	SDO(LCD)	PMUTE
EM91203A	1	1	V			V
EM91203B	√	√	V	V		V
EM91203C	√	1	√	V	V	V



EM91203



FUNCTIONAL BLOCK DIAGRAM



^{*} This specification are subject to be changed without notice.



PIN DESCRIPTIONS

Symbol	Function
ROW1~ROW4	Keyboard scan pins of row group. In idle state (HKS is "High" and HFO is "Low"),
	these pins stay "High impedance" level to prevent power consumption. Otherwise,
	these pins switch to "High" level for detecting keyboard entry. These pins will output
	600 Hz signal while keyboard is scanning.
COL1~COL3 and COL5	Keyboard scan pins of column group. In idle state, these pins stay "High impedance"
	level. Otherwise these pins switch to "Low" level for detecting keyboard entry. These
	pins will output 600 Hz signal while keyboard is scanning.
COL4/KT	The fourth column group pin of the keyboard that also provides the keytone output
	. Normally, this pin stays "Low" level for detecting keyboard entry. After a valid
	keyboard entry, this pin will output keying confirmation tone that is 600 Hz signal and
	30 ms duration. While DTMF output, the key tone will be disabled. To prevent signal
****	interference, while DTMF issue, it will disable key tone output except function key.
XIN and XOUT	Oscillator input and output pins. A 3.579545 MHz crystal or ceramic resonator must
TA CLOSE	be crossed connection to XIN and XOUT pins which generate system clock.
XMUTE	The Tone/Pulse MUTE signal output pin that is NMOS open-drain output structure.
	This pin will switch to "Low" level during Tone/Pulse dialing.
X7 1 X7	Otherwise, this pin stays "High impedance" level.
V_{DD} and V_{SS}	Positive and negative power supply input pins. Recommended operating voltage from 2.0Vdc to 5.5Vdc.
HFI	Handfree inputs pin which accepts falling edge signal to turn "on" or turn "off"
	handfree function. This pin is hysteresis input structure and built-in pull up resistor
	(typically 200 Kohms).
HFO	Handfree outputs pin that is designed to control telephone line for on-hook dialing or
	control speakerphone circuit for handfree conversation. When handfree function is
	executed, this pin will switch to "High". Otherwise, this pin stays "Low" level.
DTMF	The DTMF (Dual Tone Multi-Frequency) output pin. Normally, this pin stays"Low"
	level. In Tone dialing mode, this pin will output DTMF signal that is corresponding
	to keyboard 09, * and # keys.
HKS	Control signal inputs pin that is corresponding hook switch status. When handset was
	left from cradle, this pin must be connected to "Low" level to operate all functions.
	Otherwise, this pin must be connected to "High" level to disable all function and
	prevent power consumption.
PO	Pulse signal outputs pin that is NMOS open-drain output structure. Normally, this pin
	stays "High impedance" level. In Pulse dialing mode and keypad was entry. This pin
	will output pulse trains signal that is corresponding to keyboard 0 9 keys.
PM	Pulse signal outputs pin that is CMOS inverter output structure. Normally, this pin
	stays "Low" level. During pulse signal dialing or flash function executing, this pin will
	switch to "High" level to control the external circuit.
SDO	SDO function output that is NMOS open-drain structure. When there is a valid entry
	on keyboard, this pin will output a serial data. This serial data is designed to drive LCD
	driver to display dialing number on LCD screen or drive voice synthesizer to announce
	dialing number to speaker.
NC	No connection.



FUNCTION DESCRIPTIONS

Dialing signal selection

The EM91200s series incorporated a special keyboard scanning function that is connecting a resistor (typically is 560 Kohms) on keyboard scan pin to select many telephone specifications. The specifications are described as following:

a. Mode

ROW1	Mode
R-Vdd	20 PPS
NR	Tone
R-Vss	10 PPS

c Flash time

ROW3	ROW4	Tf (ms)
NR	NR	600
NR	R-Vss	100
R-Vss	NR	80
R-Vss	R-Vss	300

e. Pause time and P-T wait time

COL2	Tp (sec)	Tpt (ms)
NR	3.6	3.6
R-Vss	2.0	2.0

b. M/B ratio

ROW2	MBR (%)
NR	40:60
R-Vss	33:66

d. DTMF signal

	. 0	
COL1	Td (ms)	Titp (ms)
R-Vdd	90	90
NR	98	98
R-Vss	83	83

f. Keyboard operate type

COL3	Туре
NR	A
R-Vss	В

Normal dialing

Directly keying digital key on keyboard which number can be dialing output and stored in LNB memory automatically. Operating procedure described as follow:

- To select Pulse or Tone mode.
- Off-hook or turn on HF function.
- Keying <u>d1</u>, <u>d2</u>, ..., <u>dn</u>. The "d" expressed digital keypad that included 1~9, *, 0, #, P, and P→T keys. The "n" expressed unlimited.
- The numbers d1, d2, ..., dn will be dialed out in Pulse or Tone mode as selection.

LNB redial memory

Storing:

In normal dialing mode, every digital key was entry which number will be stored in LNB memory automatically. If entry digits are more than 32 digits, the redial function of LNB memory will be disabled. Otherwise, these numbers stored in LNB memory can be redial output.

Redialing:

After normal dialing, directly keying \underline{F} key (or On-Off hook once) and keying \underline{RD} key on keyboard. The numbers that are stored into LNB memory will be dialed output.

SAVE redial memory

The SAVE meomry is designed in EM91203 series to support 32 digits capacity buffer for second redial, pager, Memory and other system applications.



Storing: EM91203 series support two operating methods to store numbers into SAVE redial memory.

Method 1

- To select Pulse or Tone mode.
- Off-hook (or turn on HF function), push <u>d1, d2,</u> ..., <u>dn.</u> The numbers d1, d2, ..., dn will be dialed out in Pulse or Tone mode as selection.
- After dn had been dialed out and push <u>[ST]</u>. Save key. If the keying numbers are more than 32 digits that content of SAVE memory can not be updated. Otherwise, these numbers will be stored into SAVE memory. In the [] key allows to be omitted.

Method 2

Off-hook (or turn on HF function), push <u>ST</u>, <u>d1</u>, <u>d2</u>, ..., dn, <u>[ST]</u>, <u>Save</u>. If the keying numbers are not over 32 digits, the numbers d1, d2, ..., dn will be stored in SAVE redial memory automatically.

Dialing:

- To select Pulse or Tone mode.
- Off-hook (or turn on HF function), push <u>Save</u> key. The numbers stored in SAVE memory will be dialed out in Pulse or Tone mode as selection.

Repertory memory

The EM91203 series incorporated several sets repertory memory and each one can store number up to 16 digits. As in memory storing, if stored numbers are more than 16 digits that only the previous 16 digits can be stored into specific memory. Otherwise, these numbers can be stored entirely. After memory dialed out, the content of LNB is keeping to current data.

Storing of 3 sets memory

Direct (one-touch) operation

Off-hook (or turn on HF function), push <u>ST, d1, d2, ..., dn [ST], EMn.</u> The numbers d1, d2, ..., dn will be stored into memory location "EMn". The "EMn" expressed emergency memory EM1 to EM3.

Dialing (after memory dialed out, the content of LNB is keeping to current data)

Direct (one-touch) memory operation

- To select Pulse or Tone mode.
- Off-hook (or Turn on HF function), push <u>EMn</u> key. The numbers that are stored in direct memory location EMn will be dialed out in Pulse or Tone mode as selection. The "n" expressed digital number from 1~3 decided by dialers' memory sets.

Pause (P) key operation

The Pause (P) key is designed to support pause operation in dialing duration. "P" key can be stored in memory and it will occupy one digital position.



- To select Pulse or Tone mode.
- Off-hook (or turn on HF function), push <u>d1</u>, <u>d2</u>, ..., <u>dn</u>, <u>RD/P</u>, <u>k1</u>, <u>k2</u>, ..., <u>kn</u>. These numbers will be dialed out as following sequence:

Pulse to Tone (*/T or P-T) key operation

The Pulse to Tone (*/T or P-T) key is designed to support toll dialing (long distance call) or PABX system operation. The "*/T (or P-T)" key can be stored in memory and it will occupy one digital position.

- To select Pulse mode.
- Off-hook (or turn on HF function), push <u>d1</u>, <u>d2</u>, ..., <u>dn</u>, */T, (<u>or P-T</u>) <u>k1</u>, <u>k2</u>, ..., <u>kn</u>. These numbers will be dialed out as following sequence:

Flash (F) key operation

The Flash (F) key is designed to break telephone line temporarily. After F key is depressed, this dialer will send a flash signal to break line 600 ms, 300 ms, 100 ms or 80 ms as ROW3 and ROW4 selection.

Handfree (HF) function

The handfree function is designed to support on-hook dialing and loudspeaker application which can be turn "on" or "off" with falling edge signal from HFI pin. During handfree function is executed, the HFO pin is switched to "high". Otherwise the HFO pin stays "low" level.

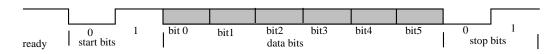
Truth table

Operating state	Input/Output pin level							
	HKS	PO	XMUTE	PM	HFO			
(0) On-hook, idle state	Н	F	F	L	L			
(1) Off-hook line	L	F	F	L	L			
(2) Off-hook, HF line	L	F	F	L	Н			
(3) On-hook, HF line	Н	F	F	L	Н			

Note: F=floating (high impedance); H=logic "High"; L=logic "Low" level.

SDO (Serial Data Output) function

The SDO is serial data output which format is same as UART protocol. SDO function is designed to drive LCD driver and voice synthesizer. So the dialing numbers can be display on LCD screen with EM32100 (or EM32116). The SDO signal consists of two start bits, six data bits and two stop bits. Each bit time is about 3.9 ms (256 Hz) and output sequences are following by start bits, data bits (LSB to MSB) and stop bits.





SDO Keypad Encoded table:

◆ Digital key (b5,b4=0,0)

keypad	1	2	3	4	5	6	7	8	9	0	"*"/T	#	P	*/"T" or P-T
output														
b3,b2,b1,b0	0001	0010	0011	0100	0101	0110	0111	1000	1001	1010	1011	1100	1101	1110
Display	1	2	3	4	5	6	7	8	9	0	L		P	-

♦ Function key (b5,b4=1,0)

keypad	F
output	
b3,b2,b1,b0	1111
Display	clear all display

* Keypad,SDO format and LCD display reference table:

Keypad	bit5	bit4	bit3	bit2	bit1	bit0	Display
1	0	0	0	0	0	1	1
2	0	0	0	0	1	0	2
3	0	0	0	0	1	1	3
4	0	0	0	1	0	0	4
5	0	0	0	1	0	1	5
6	0	0	0	1	1	0	6
7	0	0	0	1	1	1	7
8	0	0	1	0	0	0	8
9	0	0	1	0	0	1	9
0	0	0	1	0	1	0	0
"*"/T	0	0	1	0	1	1	
#	0	0	1	1	0	0	
P	0	0	1	1	0	1	P
*/"T" or P-T	0	0	1	1	1	0	_
F	1	0	1	1	1	1	clear all display



$\textbf{ABSOLUTE MAXIMUM RATINGS} (Ambient temperature is 25 \, ^{\circ}\text{C}, all voltages referenced to } V_{ss})$

Items	Sym.	Rating	Unit
Power supply voltage	V _{DD}	6.0 Vdc	V
Input voltage range	V _{IN}	V_{SS} -0.3V ~ V_{DD} +0.3V	V
Operating temperature	T_{OPR}	0 ~ +50	°C
Storage temperature	T _{STO}	-55 ~ 125	°C
Power consumption	$P_{_{\mathrm{D}}}$	500	mW

ELECTRICAL CHARACTERISTICS

(Ambient temperature is 25 °C, $V_{\tiny DD}$ =2.5V unless otherwise noted, all voltages referenced to $V_{\tiny SS}$, Fosc=3.579545 MHz)

Parameter	Sym.	Min.	Typ	Max.	Unit	Condition	
	Sym.		Typ.				
Operating voltage	Pulse		2.0	-	5.5	V	unload
	Tone		2.0	-	5.5		
Operating current(\overline{HKS} =0)	Pulse	Idd	-	0.15	0.3		unload
	Tone		-	0.3	0.5	mA	
	Pulse		-	0.15	0.3		with pull up/down
	Tone		-	0.3	0.5		resistor * 8
Memory retention current		Imrt	-	0.001	0.1	uA	HKS=1,Vdd=1V
Standby current	HKS=1	Istby	-	0.001	0.1		unload
	HKS=0		-	1	10	uA	
	HKS=1			-0.001	0.1		with pull up/down
	HKS=0		-	10	30		resistor * 8
HKS, HFI		ViH	0.8Vdd	-	Vdd	V	
pins: input voltage		ViL	Vss	-	0.2Vdd		
HFO & PM pins source current		IoH	0.2	-	-	mA	Vo = 2.0 V
\overline{PO} , HFO, \overline{XMUTE} ,		IoL	-0.2	-	-	mA	Vo = 0.5 V
& PM, SDO pins: sink current							
\overline{PO} , \overline{XMUTE} and SDO		IoH	-	-	±0.001	uA	Vo = Vdd
pins: leakage current							
HFI pin input resistance	Rhfi	-	200	-	ΚΩ	Vhfi = Vss	
Keyboard scanning pins	IoH	2	10	50	uA	Vksn=Vss	
output current (except COL4/KT)	IoL	200	400	800		Vksn=Vdd	
COL4/KT source current	IoH	0.2	-	-	mA	Vo=2.0V	
sink current		IoL	0.2	-	-		Vo=0.5V



ELECTRICAL CHARACTERISTIC

 $(Ambient\ temperature\ is\ 25^{\circ}C,\ V_{\tiny DD}=2.5V\ unless\ otherwise\ noted,\ all\ voltages\ referenced\ to\ Vss,Fosc=3.579545\ MHz)$

Keyboard debounce time Tdb - 20 - ms Key tone signal: frequency present duration Fkt - 600 - Hz Pause time and pulse to tone Tp - 3.6 - sec. COL2=NR Flash time Tf - 600 - geo. COL2=R-Vss Flash time Tf - 600 - ms Row3, Row4=R-Vss, NR - 300 - ms Row3, Row4=R-Vss, NR Row3, Row4=R-Vss, R-Vss Flash pause time Tfp - 300 - ms Make/Break ratio MBR - 40:60 - % Row1 = R-Vdd Inter-digit pause time Tidp - 800	Parameter	Sym.	Min.	Typ.	Max.	Unit	Condition
Fix Fix	Keyboard debounce time	Tdb	-	20	-	ms	
Pause time and pulse to tone Tp - 3.6 - sec. COL2=NR Tpt - 2 - sec. COL2=R-Vss Flash time Tf - 600 - Row3, Row4=NR, NR - 100 - ms Row3, Row4=NR, NR - 300 - Row3, Row4=R-Vss, NR - 300 - ms Row3, Row4=R-Vss, NR Row3, Row4=R-Vss Row1 = R-Vdd Row1 = R-Vs Row2 = NR Row2 = NR Row2 = NR Row2 = R-Vss Row2 = R-Vss Row2 = R-Vss Row3 = Row2 = Row2 = NR Row4 = R-Vs Row5 = Row4 = Row4 Row5 = Row4 = Row4 Row5 = Row5 = Row4 Row5 = Row5 = Row5 Row5	Key tone signal:						
Pause time and pulse to tone Tp - 3.6 - sec. COL2=NR Tpt - 2 - sec. COL2=R-Vss Flash time Tf - 600 - Row3, Row4=NR, NR - 100 - ms - 80 - Row3, Row4=R-Vss, NR Row3 Row1 = R-Vdd Row1 = R-Vss Row2 = NR Row2 = R-Vss Row2 = R-Vss Row2 = R-Vss Row2 = R-Vss Row3 Row4 = R-Vss Row2 = R-Vss Row2 = R-Vss Row3 Row4 = R-Vss Row2 = R-Vss Row4 = R-Vss Row4 = R-Vss Row3 Row4 = R-Vss Row4 Row1 Row4 Row1 Row4 Row1 Row4 Row5 Row2 Row5 Row5 Row5	frequency	Fkt	-	600	_	Hz	
Tpt - 2 - sec. COL2=R-Vss	present duration	Tkt	-	30	-	ms	
Flash time	Pause time and pulse to tone	Тр	-	3.6	-	sec.	COL2=NR
- 100 - ms Row3, Row4=NR, R-Vss Row3, Row4=R-Vss, NR Row3, Row4=R-Vss, R-Vss Row1 = R-Vdd Row1 = R-Vss Row2 = NR Row2 = NR Row2 = NR Row2 = R-Vss Row2 = Row2 = R-Vss Row2 = Row2 = R-Vss Row2 = Ro		Tpt	-	2	-	sec.	COL2=R-Vss
Comparison of the companies Comparison of the companies Comparison of the companies	Flash time	Tf	-	600	-		Row3, Row4=NR, NR
Flash pause time			_	100	-	ms	Row3, Row4=NR, R-Vss
Flash pause time Tfp - 300 - ms Pulse rate PSR - 20 - pps Row1 = R-Vdd Make/Break ratio MBR - 40:60 - % Row2 = NR Make/Break ratio MBR - 40:60 - % Row2 = NR Row2 = R-Vss Row2 = R-Vss Row2 = R-Vss PSR = 10 pps PSR = 20 pps DTMF pin: sink current IoL -0.2 - - mA Vdtmf = 0.5 V DTMF signal DC level Vdc 0.5 - 0.75 Vdd Vdd = 2.0V ~ 5.5V DTMF signal: ac level Vdtmf 142 160 180 mVrms Row group pre-emphase Twist 1 2 3 dB Column - Row distortion THD - -30 -23 dB RL = 5 KΩ Iname transport Iname transport Row group Row group Row group Row group Row group Row group <			-	80	-		Row3, Row4=R-Vss, NR
Pulse rate PSR - 20 - pps Row1 = R-Vdd Make/Break ratio MBR - 40:60 - % Row2 = NR Inter-digit pause time Tidp - 800 - ms PSR = 10 pps DTMF pin: sink current IoL -0.2 - - mA Vdtmf = 0.5 V DTMF signal DC level Vdc 0.5 - 0.75 Vdd Vdd = 2.0V ~ 5.5V DTMF signal: ac level Vdtmf 142 160 180 mVrms Row group pre-emphase Twist 1 2 3 dB Column - Row distortion THD - -30 -23 dB RL = 5 KΩ load resistance ZL 5 - - KΩ THD <-23dB			-	300	-		Row3, Row4=R-Vss,R-Vss
Make/Break ratio MBR - 40:60 - % Row1 = R-Vss	Flash pause time	Tfp	-	300	-	ms	
	Pulse rate	PSR	-	20	-	pps	Row1 = R-Vdd
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			-	10	-	Ī	Row1 = R-Vss
	Make/Break ratio	MBR	-	40:60	-	%	Row2 = NR
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			-	33:66	-		Row2 = R-Vss
	Inter-digit pause time	Tidp	-	800	-	ms	PSR = 10 pps
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			-	500	-		PSR = 20 pps
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	DTMF pin: sink current	IoL	-0.2	-	-	mA	Vdtmf = 0.5 V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	DTMF signal DC level	Vdc	0.5	-	0.75	Vdd	$Vdd = 2.0V \sim 5.5V$
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	DTMF signal: ac level	Vdtmf	142	160	180	mVrms	Row group
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	pre-emphase	Twist	1	2	3	dB	Column - Row
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	distortion	THD	-	-30	-23	dB	$RL = 5 K\Omega$
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	load resistance	ZL	5	-	-	ΚΩ	THD <-23dB
81 83 85			96	98	100		
Minimum inter-tone pause Titp 88 90 92 ms Memory dialing	Minimum tone duration	$T_{_{ m D}}$				ms	Memory dialing
Minimum inter-tone pause Titp 88 90 92 ms Memory dialing							
		60.				-	
01 03 03	Minimum inter-tone pause	Litp				ms	Memory dialing
SDO every bit time Tbit 3.8 3.9 4.1 ms	SDO every bit time	Thit				ms	

DTMF output frequency (fosc = 3.579545 MHz)

Keyboard scan pin	CCITT standard (Hz)	Actual output (Hz)	Deviation (%)
ROW1 (f1)	697	699.1	0.30
ROW2 (f2)	770	766.2	0.49
ROW3 (f3)	852	847.4	-0.53
ROW4 (f4)	941	947.9	0.73
COL1 (f5)	1209	1215.8	0.56
COL2 (f6)	1336	1331.6	-0.32
COL3 (f7)	1477	1471.8	-0.35

^{*} This specification are subject to be changed without notice.



TIMING DIAGRAM

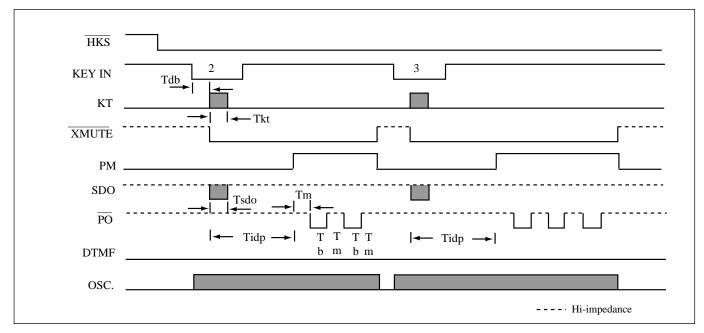


Figure 1. Pulse mode operating timing

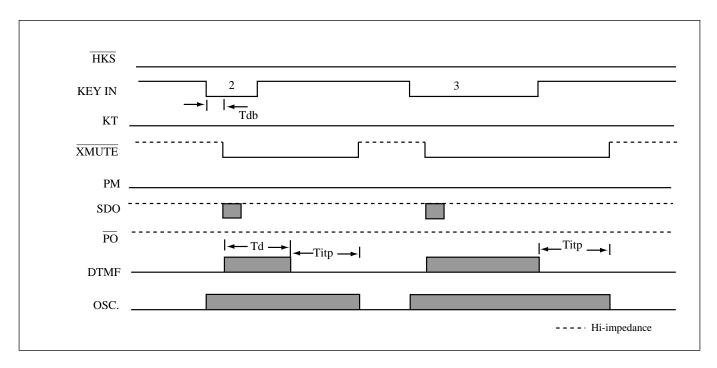


Figure 2. DTMF mode operating timing



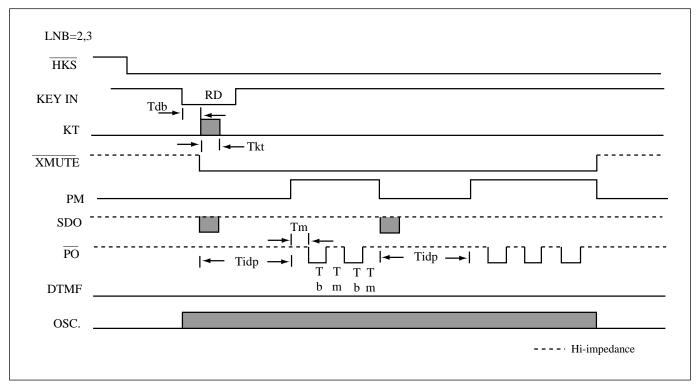


Figure 3. Pulse mode LNB redial timing

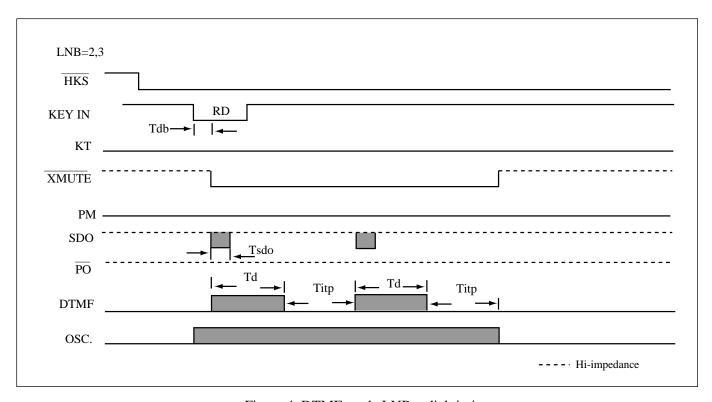


Figure 4. DTMF mode LNB redial timing



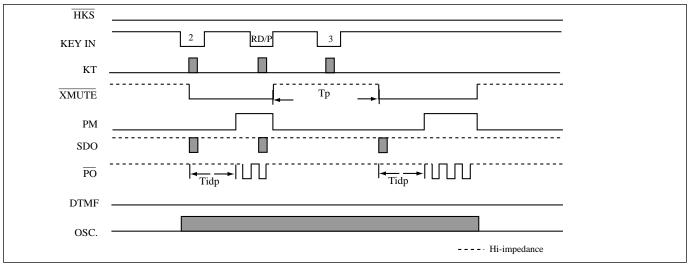


Figure 5. Pause key operating timing

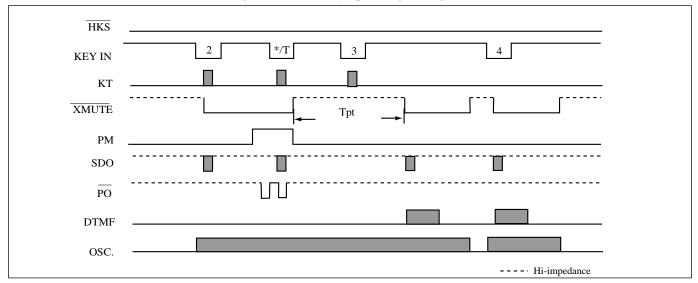


Figure 6. Pulse to Tone $(P \rightarrow T)$ operating timing

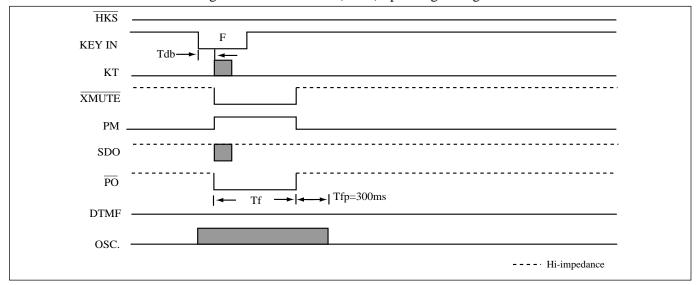
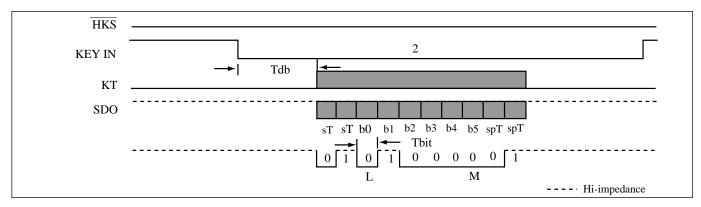


Figure 7. Flash key operating timing





<Note>L=LSB,M=MSB, sT=START bit time, spT=STOP bit time Figure 8. SDO operating timing

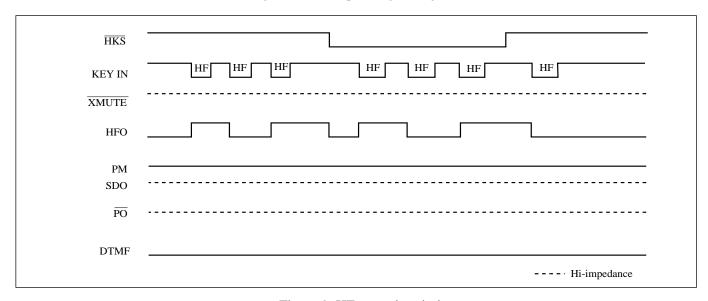
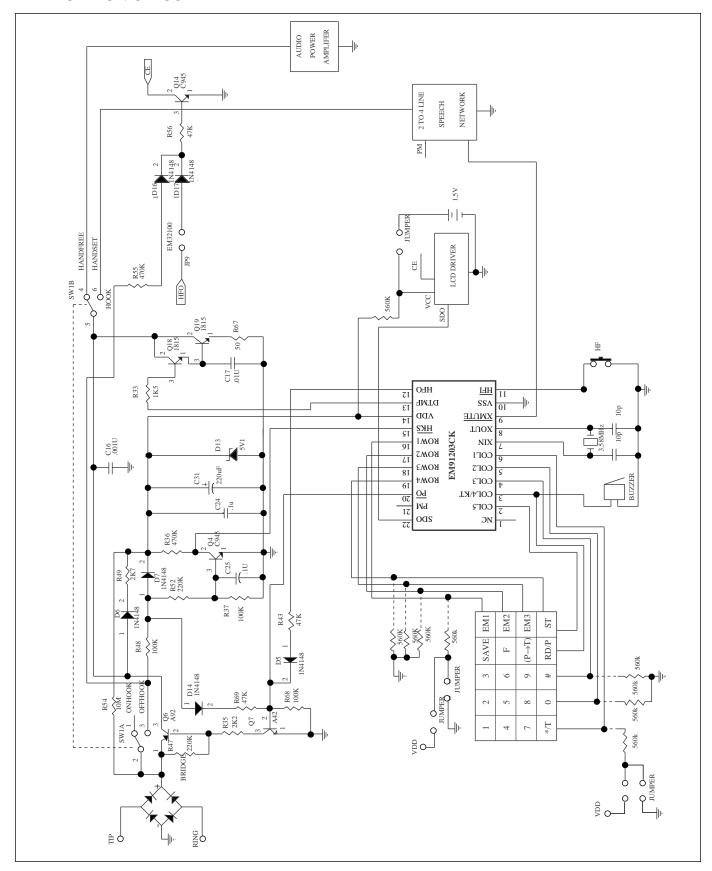


Figure 9. HF operating timing

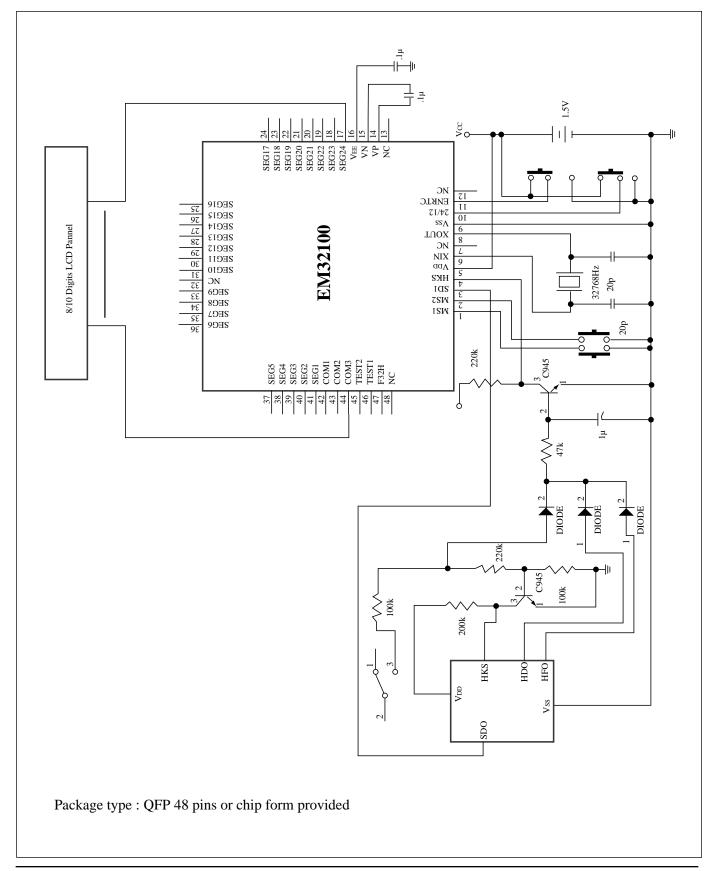


APPLICATION CIRCUIT



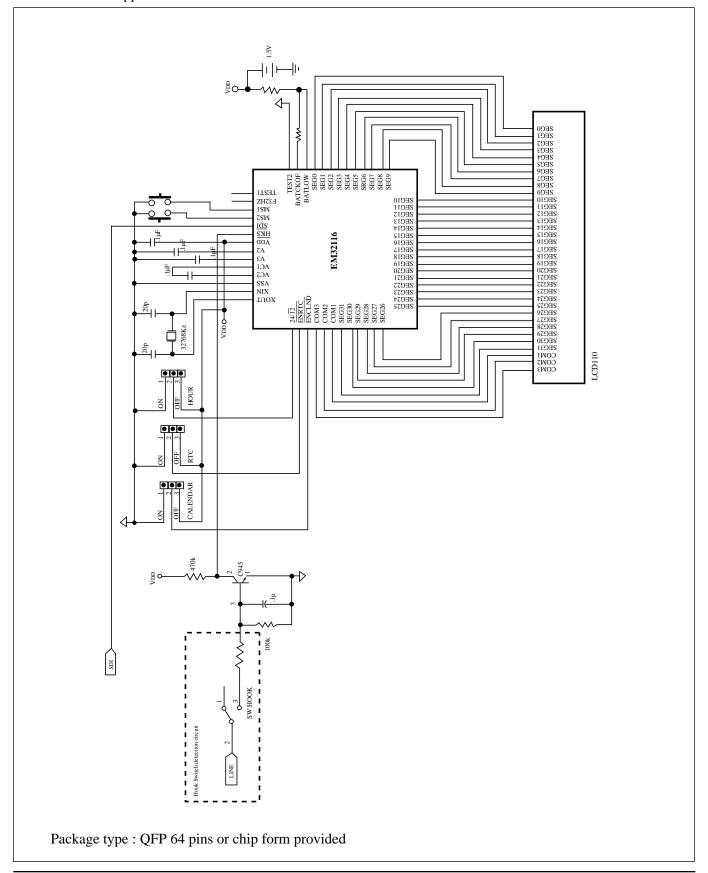


EM32100 Application Circuit:





EM32116 Application Circuit:





PACKAGE INFORMATION

Example:

<u>EM</u> <u>91203</u> <u>P</u> (3) (1) (2)

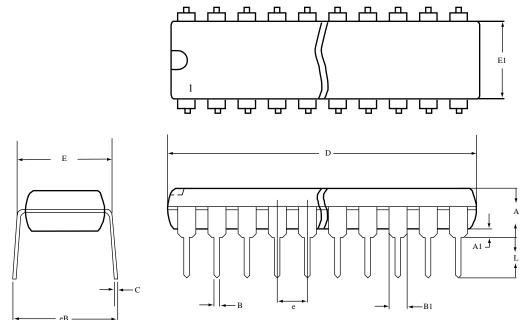
- (1) ELAN MICRO. pefix
- (2) Type number
- (3) Package code:

P→PDIP

 $K \rightarrow Skinny$

 $R\rightarrow SDIP$

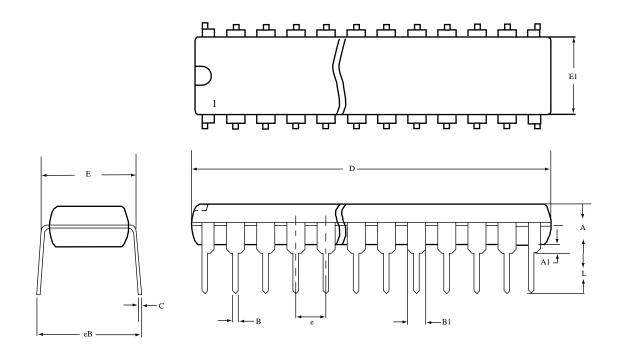
18/20/28 Lead Plastic Package



	← eB →													
18 PDIP					20 PDIP							4	28 PDI	P
	MILIME	ETERS	INC	CHES		MILIM	ETERS	INC	HES		MILIM	ETERS	INC	HES
DIM	MIN.	MAX.	MIN.	MAX.	DIM	MIN.	MAX.	MIN.	MAX.	DIM	MIN.	MAX.	MIN.	MAX.
A	-	5.334	-	.210	A	-	5.334	-	.210	A	-	6.350	-	.250
A1	0.381	-	.015	-	A1	0.381	-	.015	-	A1	0.381	-	.015	-
В	0.356	0.558	.014	.022	В	0.356	0.558	.014	.022	В	0.356	0.558	.014	.022
B1	1.150	1.778	.045	.070	B1	1.150	1.778	.045	.070	B1	1.016	1.778	.040	.070
C	0.204	0.381	.008	.015	С	0.204	0.381	.008	.015	C	0.204	0.381	.008	.015
D	22.35	23.37	.880	.920	D	25.40	26.67	1.000	1.050	D	35.56	37.85	1.400	1.490
Е	7.620	8.255	.300	.325	Е	7.620	8.255	.300	.325	Е	15.24	15.88	.600	.625
E1	6.096	7.112	.240	.280	E1	6.096	7.112	.240	.280	E1	13.21	14.73	.520	.580
e	2.286	2.794	.090	.110	e	2.286	2.794	.090	.110	e	2.286	2.794	.090	.110
eB	-	10.92	-	.430	eВ	-	10.92	-	.430	eB	-	17.78	-	.700
L	2.921	4.064	.115	.160	L	2.921	4.064	.115	.160	L	2.921	5.080	.115	.200



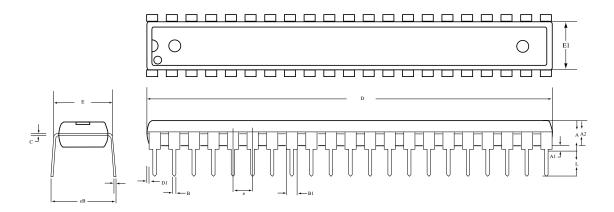
22/24 Lead Plastic Package-Skinny



	22 PDIP (skinny)					24 PDIP (skinny)					
	MILIME	TERS	INCH	IES		MILIMETERS INCHES			HES		
DIM	MIN.	MAX.	MIN.	MAX.	DIM	MIN.	MAX.	MIN.	MAX.		
A	-	4.752	-	.180	A	-	4.572	1	.180		
A1	0.381	-	.015	-	A1	0.381	-	.015	-		
В	0.356	0.558	.014	.022	В	0.356	0.558	.014	.022		
B1	1.27	1.778	.050	.070	B1	1.27	1.778	.050	.070		
C	0.204	3.556	.008	.014	C	0.204	0.381	.008	.015		
D	25.90	26.67	1.02	1.05	D	31.24	32.26	1.23	1.270		
Е	7.620	8.255	.300	.325	Е	7.620	8.255	.300	.325		
E1	6.223	6.604	.245	.260	E1	6.223	6.731	.245	.265		
e	2.286	2.794	.090	.110	e	2.286	2.794	.090	.110		
eB	8.382	10.16	.330	.400	eВ	8.636	9.652	.340	.380		
L	2.921	4.064	.115	.160	L	2.921	4.064	.115	.160		



42 SDIP Package



42 SDIP									
	MILIME	ETERS	INC	HES					
DIM	MIN.	MAX.	MIN.	MAX.					
A	-	5.08	-	0.200					
A1	0.381	-	0.015	-					
A2	3.937	4.191	0.155	0.165					
В	0.356	0.559	0.014	0.022					
B1	0.914	1.116	0.036	0.044					
C	0.204	0.304	0.008	0.012					
D	36.70	37.34	1.445	1.470					
E1	13.84	14.10	0.545	0.555					
e	1.727	1.829	0.068	0.072					
eB	15.24	17.78	0.600	0.70					
D1	0	0.127	0	0.005					
L	2.921	3.429	0.115	0.135					